



#### 60V N-Channel Enhancement Mode MOSFET - ESD Protected

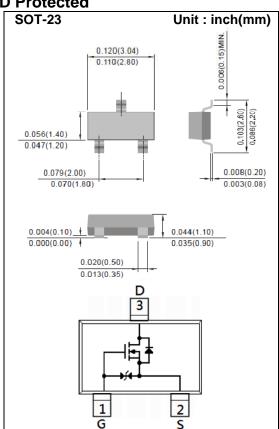
Voltage 60 V Current 300mA

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_{D}@500mA<3\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@200mA<4\Omega$
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Very Low Leakage Current In Off Condition
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V <sub>DS</sub>	60	V		
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 20			
Continuous Drain Current (Note 4)		I <sub>D</sub>	300	mA	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	2000		
Power Dissipation	T <sub>A</sub> =25°C		500	mW	
	Derate above 25°C	P <sub>D</sub>	4	mW/°C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 3,4)		Reja	250	°C/W	





### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =10uA 60 -	-	-	.,,	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	-	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =500mA	-	-	3	Ω
		V <sub>GS</sub> =4.5V,I <sub>D</sub> =200mA	-	-	4	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V - V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V -	-	-	1	
Gate-Source Leakage Current	I <sub>GSS</sub>		-	<u>+</u> 10	uA	
Forward Transconductance	<b>G</b> fs	V <sub>DS</sub> =15V, I <sub>D</sub> =250mA	100	-	-	mS
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =250mA, V <sub>GS</sub> =5V (Note 1,2)	-	0.8	-	nC
Gate-Source Charge	$Q_gs$		-	0.35	-	
Gate-Drain Charge	$Q_gd$		-	0.2	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHZ	-	35	-	pF
Output Capacitance	Coss		-	13	-	
Reverse Transfer Capacitance	Crss	I=IIVINZ	-	8	-	
Turn-On Delay Time	td <sub>(on)</sub>	.,	-	2.7	-	ns
Turn-On Rise Time	tr	$V_{DD}$ =30V, $I_{D}$ =200mA, $V_{GS}$ =10V, $R_{G}$ =10 $\Omega$ (Note 1,2)	-	19	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	15	-	
Turn-Off Fall Time	tf	NG-1002 (***********************************	-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	300	mA
Diode Forward Voltage	V <sub>SD</sub>	Is=200mA, V <sub>GS</sub> =0V	-	0.82	1.3	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

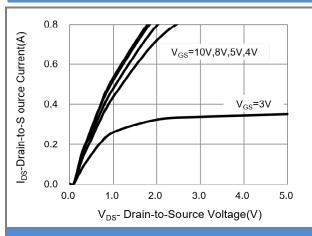


Fig.1 On-Region Characteristics

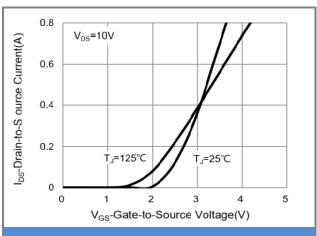


Fig.2 Transfer Characteristics

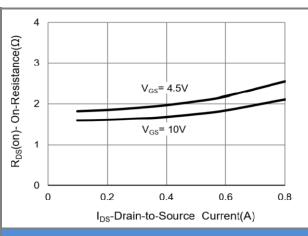


Fig.3 On-Resistance vs. Drain Current

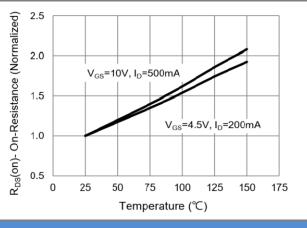
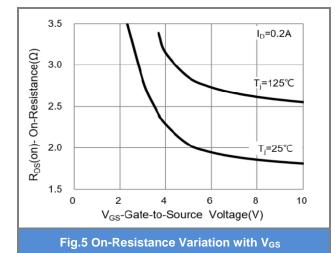
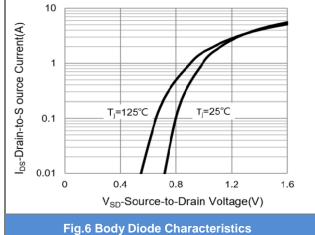


Fig.4 On-Resistance vs. Junction temperature









### **TYPICAL CHARACTERISTIC CURVES**

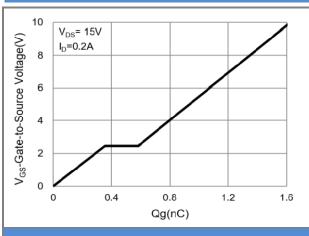


Fig.7 Gate-Charge Characteristics

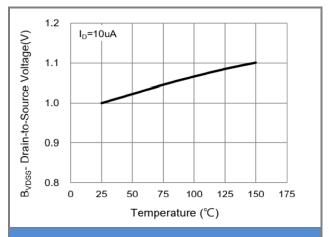


Fig.8 Breakdown Voltage Variation vs. Temperature

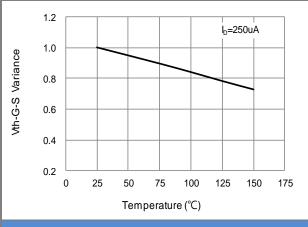


Fig.9 Threshold Voltage Variation with Temperature

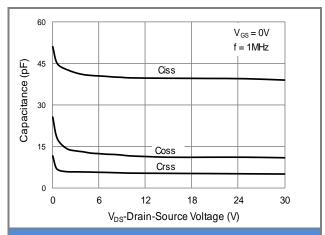


Fig.10 Capacitance vs. Drain-Source Voltage

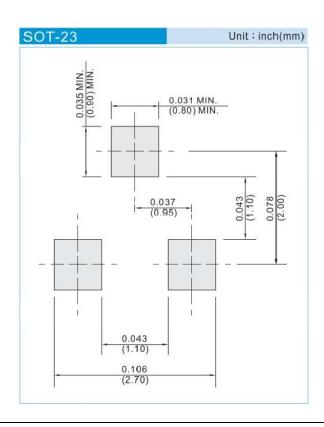




## Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
2N7002K-AU_R1_000A2	SOT-23	3K pcs / 7" reel	K72	Halogen free

### **Mounting Pad Layout**







### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
  responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
  representation or warranty that such applications will be suitable for the specified use without further testing or
  modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.